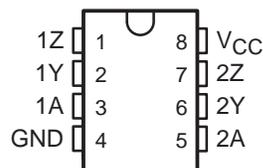


# SN75158 DUAL DIFFERENTIAL LINE DRIVER

SLLS085B – JANUARY 1977 – REVISED MAY 1995

- Meets or Exceeds the Requirements of ANSI EIA/TIA-422-B and ITU Recommendation V.11
- Single 5-V Supply
- Balanced-Line Operation
- TTL Compatible
- High Output Impedance in Power-Off Condition
- High-Current Active-Pullup Outputs
- Short-Circuit Protection
- Dual Channels
- Input Clamp Diodes

D, P, OR PS† PACKAGE  
(TOP VIEW)



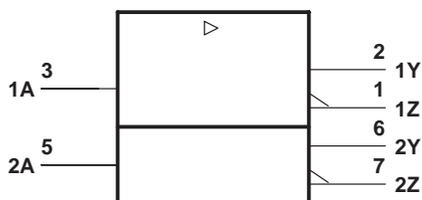
† The PS package is only available left-end taped and reeled, i.e., order SN75158PSLE.

## description

The SN75158 is a dual differential line driver designed to satisfy the requirements set by the ANSI EIA/TIA-422-B and ITU V.11 interface specifications. The outputs provide complementary signals with high-current capability for driving balanced lines, such as twisted pair, at normal line impedance without high power dissipation. The output stages are TTL totem-pole outputs providing a high-impedance state in the power-off condition.

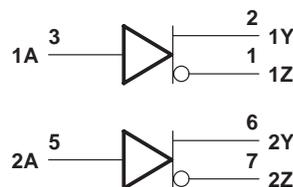
The SN75158 is characterized for operation from 0°C to 70°C.

## logic symbol‡



‡ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## logic diagram (positive logic)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS  
INSTRUMENTS**

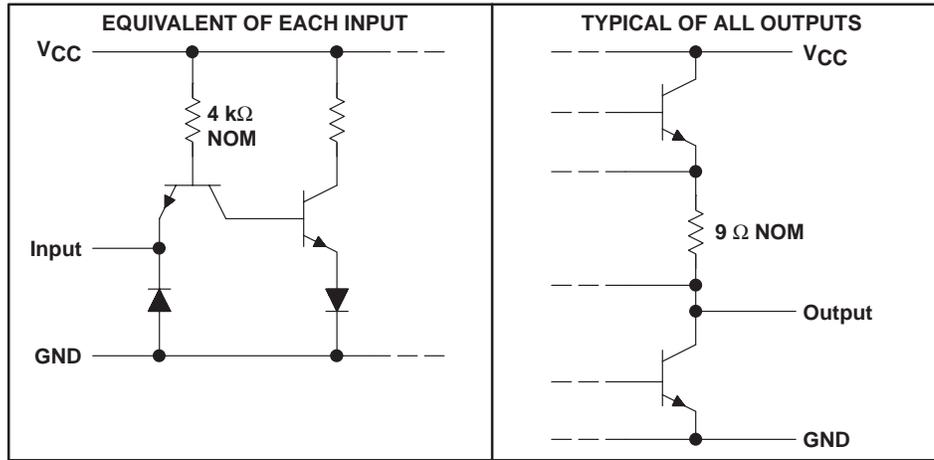
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# SN75158 DUAL DIFFERENTIAL LINE DRIVER

SLLS085B – JANUARY 1977 – REVISED MAY 1995

## schematics of inputs and outputs



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, $V_{CC}$ (see Note 1)	7 V
Input voltage, $V_I$	5.5 V
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, $T_A$	0°C to 70°C
Storage temperature range, $T_{stg}$	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential output voltage  $V_{OD}$ , are with respect to network ground terminal.  $V_{OD}$  is at the Y output with respect to the Z output.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW
P	1000 mW	8.0 mW/°C	640 mW
PS	450 mW	3.6 mW/°C	288 mW

### recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, $V_{CC}$	4.75	5	5.25	V
High-level input voltage, $V_{IH}$	2			V
Low-level input voltage, $V_{IL}$			0.8	V
High-level output current, $I_{OH}$			-40	mA
Low-level output current, $I_{OL}$			40	mA
Operating free-air temperature, $T_A$	0		70	°C



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**electrical characteristics over operating free-air temperature range (unless otherwise noted)**

PARAMETER		TEST CONDITIONS†	MIN	TYP‡	MAX	UNIT
V <sub>IK</sub>	Input clamp voltage	V <sub>CC</sub> = MIN, I <sub>I</sub> = -12 mA	-0.9	-1.5		V
V <sub>OH</sub>	High-level output voltage	V <sub>CC</sub> = MIN, V <sub>IH</sub> = 2 V, V <sub>IL</sub> = 0.8 V, I <sub>OH</sub> = -40 mA	2.4	3		V
V <sub>OL</sub>	Low-level output voltage	V <sub>CC</sub> = MIN, V <sub>IH</sub> = 2 V, V <sub>IL</sub> = 0.8 V, I <sub>OL</sub> = 40 mA		0.2	0.4	V
V <sub>OD1</sub>	Differential output voltage	V <sub>CC</sub> = MAX, I <sub>O</sub> = 0		3.5	2×V <sub>OD2</sub>	V
V <sub>OD2</sub>	Differential output voltage	V <sub>CC</sub> = MIN	2	3		V
ΔV <sub>OD</sub>	Change in magnitude of differential output voltage§	V <sub>CC</sub> = MIN		±0.02	±0.4	V
V <sub>OC</sub>	Common-mode output voltage¶	V <sub>CC</sub> = MAX		1.8	3	V
		V <sub>CC</sub> = MIN		1.5	3	
ΔV <sub>OC</sub>	Change in magnitude of common-mode output voltage§	V <sub>CC</sub> = MIN or MAX		±0.02	±0.4	V
I <sub>O</sub>	Output current with power off	V <sub>CC</sub> = 0	V <sub>O</sub> = 6 V	0.1	100	μA
			V <sub>O</sub> = -0.25 V	-0.1	-100	
			V <sub>O</sub> = -0.25 to 6 V		±100	
I <sub>I</sub>	Input current at maximum input voltage	V <sub>CC</sub> = MAX, V <sub>I</sub> = 5.5 V			1	mA
I <sub>IH</sub>	High-level input current	V <sub>CC</sub> = MAX, V <sub>I</sub> = 2.4 V			40	μA
I <sub>IL</sub>	Low-level input current	V <sub>CC</sub> = MAX, V <sub>I</sub> = 0.4 V		-1	-1.6	mA
I <sub>OS</sub>	Short-circuit output current#	V <sub>CC</sub> = MAX	-40	-90	-150	mA
I <sub>CC</sub>	Supply current (both drivers)	V <sub>CC</sub> = MAX, Inputs grounded, T <sub>A</sub> = 25°C, No load		37	50	mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C except for V<sub>OC</sub>, for which V<sub>CC</sub> is as stated under test conditions.

§ ΔV<sub>OD</sub> and Δ|V<sub>OC</sub>| are the changes in magnitudes of V<sub>OD</sub> and V<sub>OC</sub>, respectively, that occur when the input is changed from a high level to a low level.

¶ In ANSI Standard EIA/TIA-422-B, V<sub>OC</sub>, which is the average of the two output voltages with respect to ground, is called output offset voltage, V<sub>OS</sub>.

# Only one output should be shorted at a time, and duration of the short circuit should not exceed one second.

**switching characteristics, V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C**

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>PLH</sub>	Propagation delay time, low-to-high-level output	See Figure 2, Termination A		16	25	ns
t <sub>PHL</sub>	Propagation delay time, high-to-low-level output			10	20	ns
t <sub>PLH</sub>	Propagation delay time, low-to-high-level output	See Figure 2, Termination B		13	20	ns
t <sub>PHL</sub>	Propagation delay time, high-to-low-level output			9	15	ns
t <sub>TLH</sub>	Transition time, low-to-high-level output	See Figure 2, Termination A		4	20	ns
t <sub>TLH</sub>	Transition time, high-to-low-level output			4	20	ns
	Overshoot factor	See Figure 2, Termination C			10%	

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## PARAMETER MEASUREMENT INFORMATION

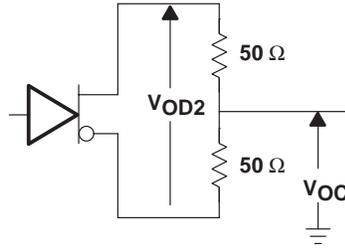
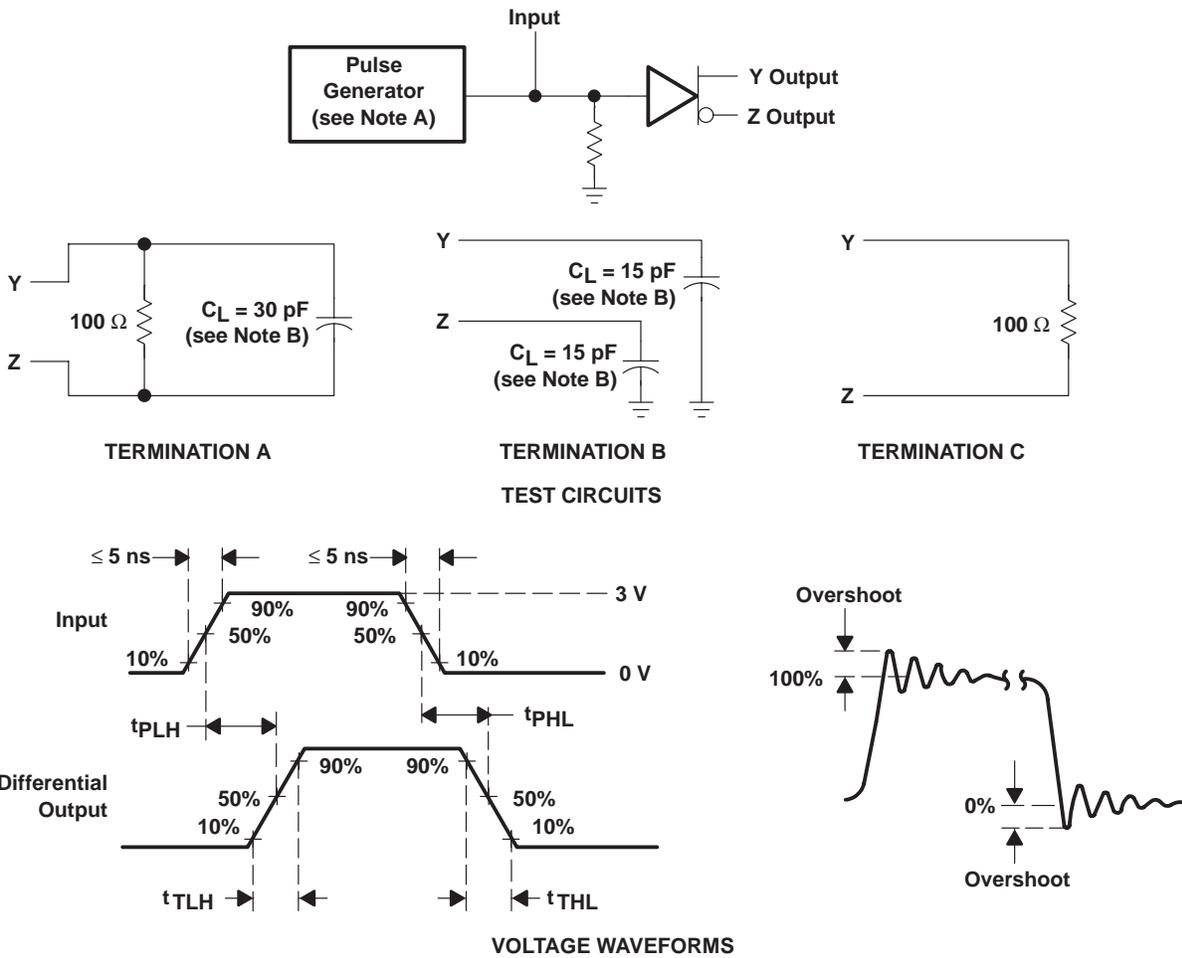


Figure 1. Differential and Common-Mode Output Voltages



NOTES: A. The pulse generator has the following characteristics:  $Z_O = 50 \Omega$ ,  $t_w = 25 \text{ ns}$ ,  $\text{PRR} \leq 10 \text{ MHz}$ .  
B.  $C_L$  includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

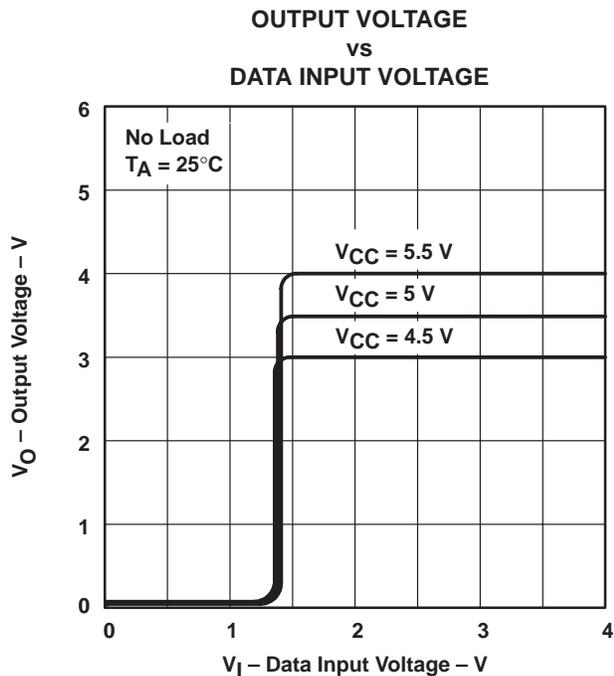


Figure 3

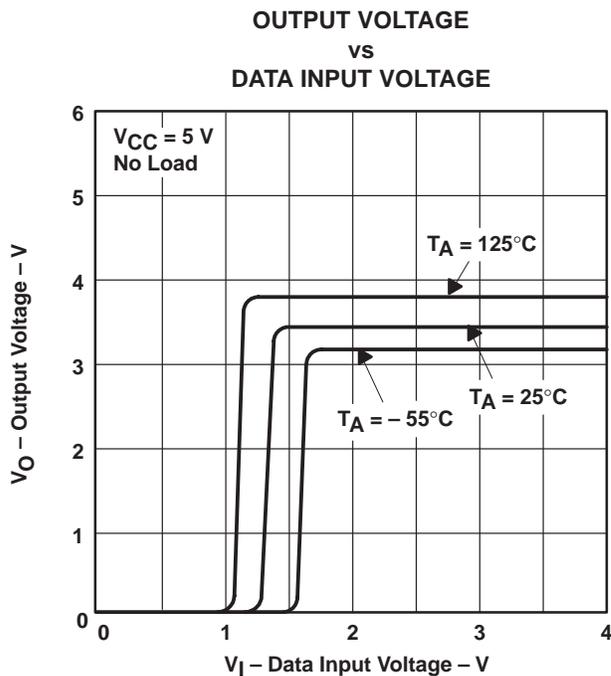


Figure 4

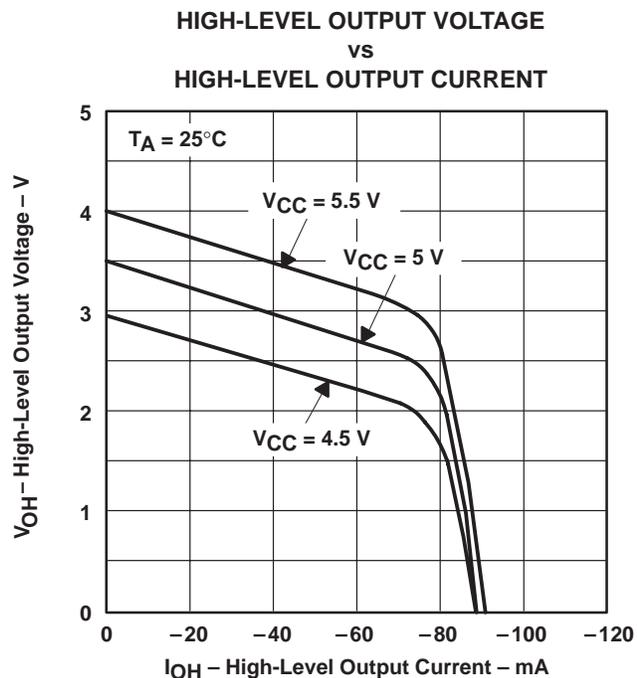


Figure 5

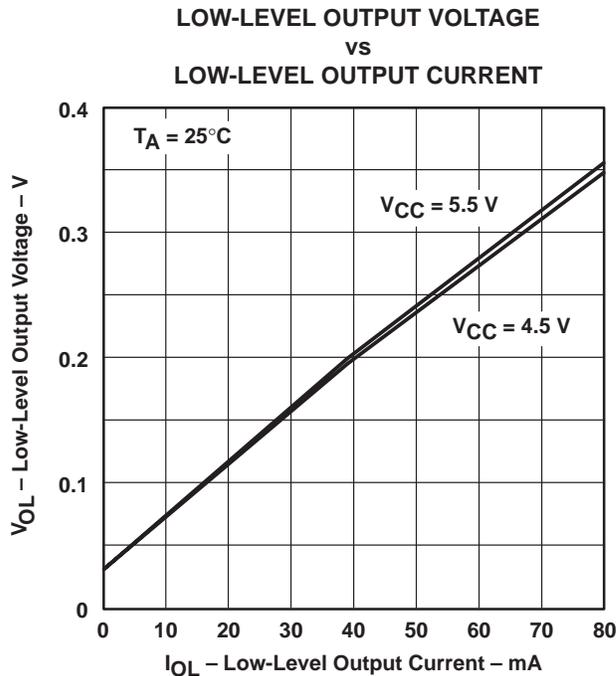


Figure 6

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## TYPICAL CHARACTERISTICS

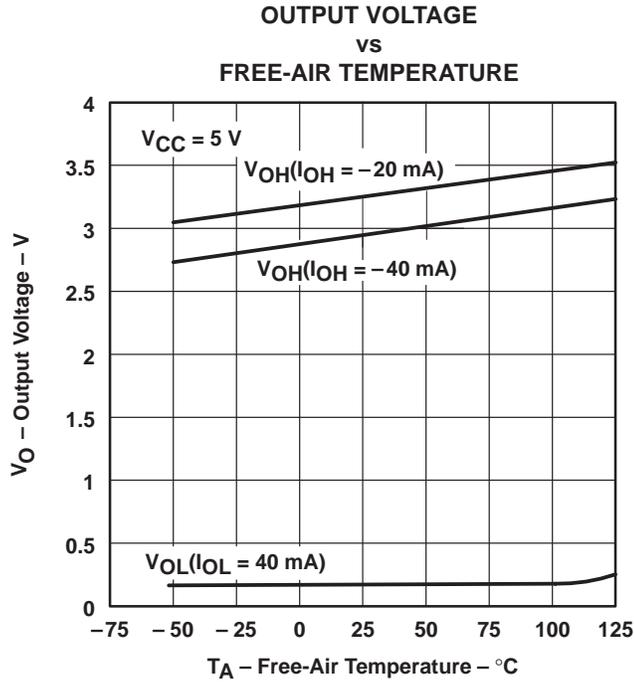


Figure 7

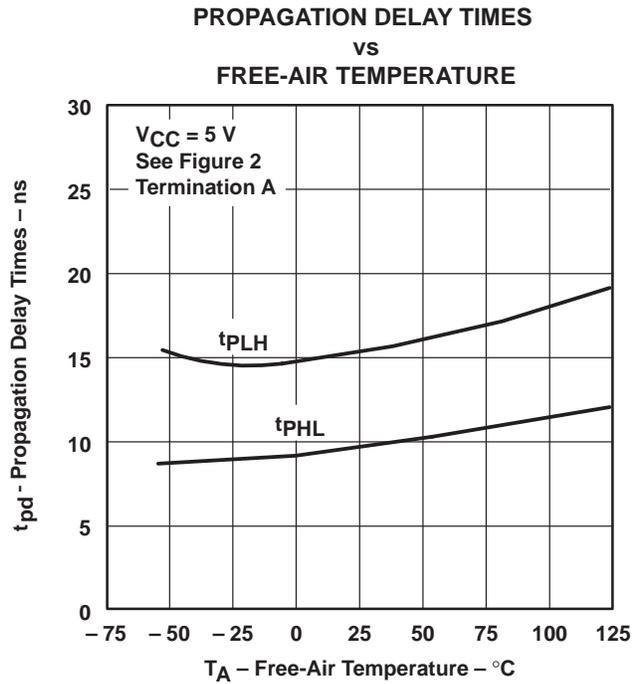


Figure 8

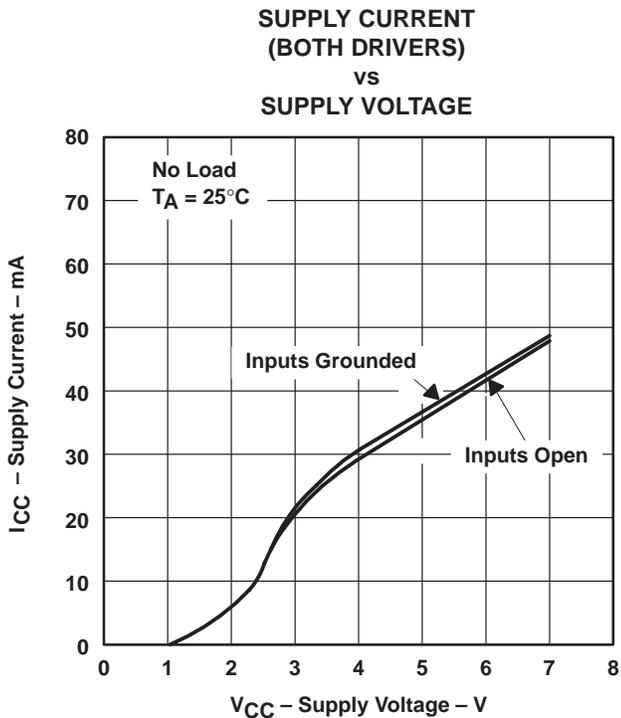


Figure 9

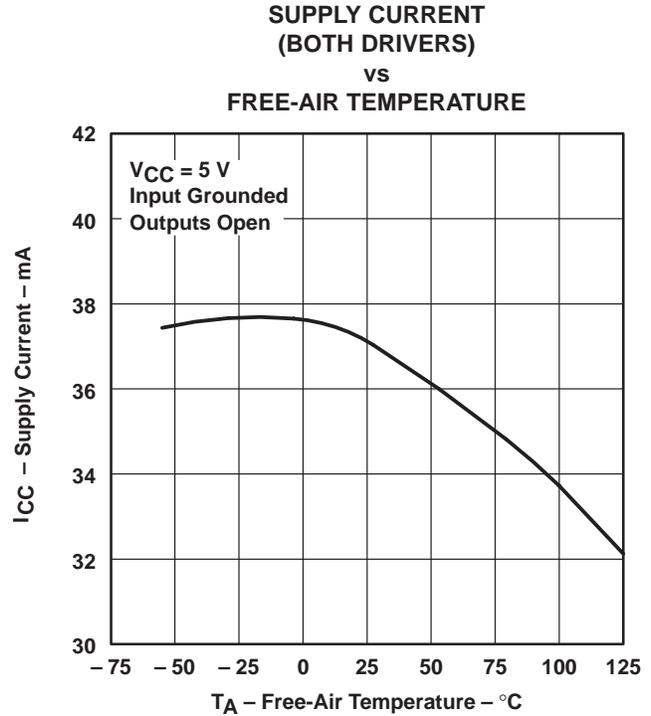


Figure 10

TYPICAL CHARACTERISTICS

SUPPLY CURRENT  
(BOTH DRIVERS)  
vs  
FREQUENCY

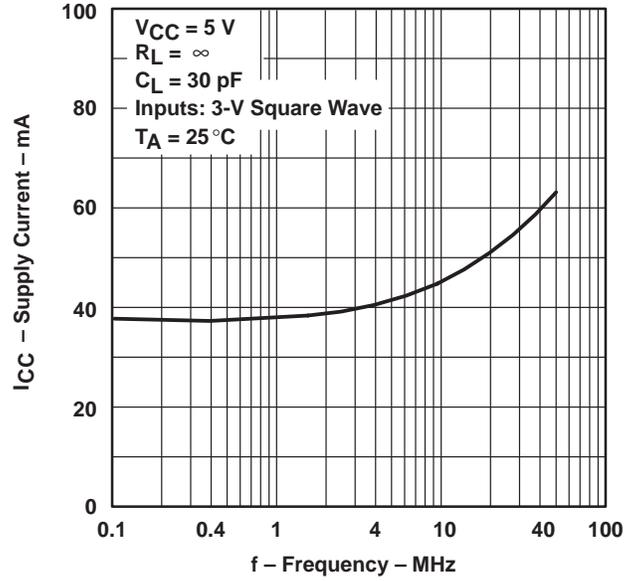


Figure 11

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